

Specification

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Ceramic Material

5 The invention concerns a ceramic material based on lead zirconate titanate (PZT).

It is preferably suited for the construction of piezoceramic multilayer components and exhibits an outstanding thermal and temporal stability of the piezoelectric characteristics under functional loading.

10 The use of such piezoceramic components as sensors or actuators, especially in automotive engineering, is due to their high reliability and temporal stability, as well as an adequate thermal stability, while at the same time having relatively large deflections when an electrical voltage is impressed. These attributes require one to establish a particular ratio of Zr to Ti in the perovskite structure ABO_3 of PZT, corresponding to the so-called
15 morphotropic phase boundary MPB. The piezoelectric properties take on especially advantageous values in the MPB composition range. Furthermore, the functional properties of the lead zirconate titanate ceramic can be adapted very much to the particular application by adding certain additives which go into solid solution in the perovskite structure. In general, one will try not to lower too much the relatively high value of the
20 Curie temperature of around 360° C, responsible for the thermal stability of the piezoelectric properties, as a result of such modifications, which can be accomplished by keeping the concentration of the additive component low.

From publication WO 97/40537 there is known a PZT ceramic which calls for a doping at the A-site of the perovskite structure to improve the properties of the ceramic. A rare earth metal, preferably lanthanum or neodymium, is chosen for the A-site doping.

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Moreover, a composition $Pb_{0.97}Nd_{0.02}[(Zr_{0.3}Ti_{0.4}(Ni_{1/3}Nb_{2/3})_{0.3})O_3]$ is known from the publication of Schuh et al., Proc. Electroceramics V, Aveiro 1996 Vol. 1, 201.

10 Furthermore, the incorporation of the compound $Sr(K_{0.25}Nb_{0.75})O_3$ in the

perovskite lattice of PZT is described in the publication DE 198 40 488 A1.

The goal of the present invention is to indicate a ceramic material that is well suited to use in piezo-actuators.

15 Furthermore, it is the goal of the invention to indicate a method for production of the ceramic material.

A ceramic material is indicated that is composed of a first ceramic material with a perovskite structure as the host lattice, containing lead, zirconium and titanium, and a 20 second ceramic material with a cryolite structure.

TRANSLATION

14219-119US1/ P2004,0032USN
PCT/DE2005/000045

Furthermore, a ceramic material is indicated that contains mixed crystals of a first ceramic material and a second ceramic material. The first ceramic material has a perovskite structure and contains lead, zirconium and titanium. The second ceramic material has a cryolite structure.

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The first ceramic material preferably corresponds to the composition $Pb(Zr, Ti)O_3$, known as PZT. The following embodiments refer primarily to the first ceramic material.

One advantageous embodiment of the ceramic material is based on a partial substitution of Pb^{II} and Zr^{IV}/Ti^{IV} in the $Pb(Zr, Ti)O_3$ ceramic with ions of comparably 10 ionic radius, such as A^{II} cations (A^{II} : Ba, Sr, Ca) at the A-sites and B^{IV} cations (B^{IV} : Sn) at the B-sites of the perovskite structure. In the framework of such a mixed crystal formation, moreover, a wide variety of modifications is possible by aliovalent substitution. This may consist of a pairwise substitution with valency compensation 15 between the A and B-sites of the perovskite structure, for example, with A^I cations (A^I : K, Ag) and B^V cations (B^V : Nb, Ta, Sb) and their combinations, or one may consider A^{III} cations (A^{III} : La^{III}, REA^{III}, Bi^{III}) and B^{III} cations (B^{III} : Al, Co, Mn) and their combinations. Mixed crystals of the mentioned three versions are also feasible.

20 Besides the pairwise coupled substitution with valency compensation, in which one can achieve a high degree of substitution, it is also possible to do a substitution without valency compensation, adhering to narrow concentration limits for the added

component. In this case, lattice sites remain unoccupied temporarily during the sintering, or even permanently. In this way, sinter compaction and grain formation are encouraged, and especially advantageous piezoelectrical and piezomechanical functional properties result when the Zr/Ti ratio is adjusted to the MPB.

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So-called soft piezoceramics with a relatively shallower trend for the ferroelectric hysteresis curve on the polarization v. field strength diagram can be achieved by incorporating higher-valency cations at the A-sites, i.e., A^{III} instead of Pb^{II}, or by incorporating higher-valency cations B^V instead of Zr^{IV}/Ti^{IV} at the B-sites, without having any valency compensation as in the case of the pairwise coupled substitution. Thanks to the vacancies created at the A-sites by reason of such a doping, the growth of grains is kinetically favored in the sintering process, as is the movement of the domain walls when an electric field is applied, which results in high values of the dielectric constant ε and large deflection amplitudes under relatively moderate field strength of around 2 kV/mm, although this also entails reduced elasticity and increased dielectric losses.

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Piezoceramic systems of this type correspond, for example, to the formula Pb_{1-3x/2}La_xV_{Pb,x/2}(Zr_{0.53}Ti_{0.47})O₃ (V_{Pb} = vacancy at Pb^{II} site) (0.005 < x < 0.02), while instead of La^{III} one can also consider other cations of the rare earth element REA^{III}, such as Nd^{III} in Pb_{1-3x/2}Nd_xV_{Pb,x/2}(Zr_{0.53}Ti_{0.47})O₃ with x = 0.02. It can be shown that such a ceramic in the multilayer component of an actuator with Ag/Pd inner electrodes after sintering in air takes on the composition Pb_{0.96}Nd_{0.02}Ag_{0.02}(Zr_{0.54}Ti_{0.46})O₃ as a result of Ag^I ions migrating

into the vacancies. Further substitutions by cations of the rare earths

$Pb_{0.97}A^{III}_{0.02}V_{Pb,0.01}(Zr_{0.535}Ti_{0.465})O_3$ with A = La, Nd, Eu, Gd, Er, and also Bi, are likewise possible. The variant of a substitution of B-sites without valency compensation in the case of niobium-doped piezoceramics occurs as $Pb_{1-x/2}V_{Pb,x/2}(Zr_{1-p}Ti_p)_{1-x}Nb_xO_3$. The complex composition of a comparatively hard piezoceramic $Pb_{0.99}V_{0.01}\{[(Zr_xSn_{1-x})_{1-y}Ti_y]_{0.98}Nb_{0.02}\}O_3$ can also be included in such a context.

So-called hard piezoceramics with a steeper ferroelectric hysteresis curve in the plot of polarization v. field strength can be produced by incorporating cations with lower valency at the A-sites, i.e., A^I instead of Pb^{II} , or by incorporating lower valency cations at the B-sites of the perovskite structure, i.e., in the latter case, B^{III} cations such as Al^{III} , Fe^{III} , Cr^{III} or Ga^{III} , or B^{II} cations such as Mg^{II} , Ca^{II} , Ni^{II} , Co^{II} or Mn^{II} instead of Zr^{IV}/Ti^{IV} . Such a doping entails, at high temperature, the formation of vacancies in the oxygen sublattice, so that in particular the sinter compaction in the thermal ceramization process undergoes a significant furtherance. But in the cooldown process the vacancies should be very extensively filled by oxygen, or else the insulation resistance and the stability to aging will be negatively affected. Hard piezoceramics, such as $Pb_{1-x}K_x(Zr_{0.65}Ti_{0.35})O_{3-x}V_{O,x/2}$ (V_O stands here for an oxygen vacancy) generally have a larger coefficient of elasticity, smaller dielectric constant ϵ , and lower dielectric losses.

The use of aliovalent substitutions without valency compensation by so-called “soft” additives, whose effect is partially offset by blending in “hard” components, has

proven to be especially advantageous for adjusting the optimal piezoelectrical and piezomechanical functional properties.

Such combinations include the mixed occupancy of the B-sites by different cations, such that valency compensation with full occupancy of all lattice sites in the perovskite lattice is once again achieved. This results in an enormous broadening of the physical modifications of PZT ceramics.

Preferably, when producing the material indicated herein, one will proceed such that compounds of suitable crystal chemistry, which crystallize in a structure derived from cryolite Na₂(Na,Al)F₆, form mixed crystals with the perovskite lattice of PZT and possibly also with mixed crystal systems without or with valency compensation.

An especially well suited compound with cryolite structure is Sr₆Nb₂O₁₁. The formulation Sr₄(Sr₂Nb₂)O₁₁, which is adapted to the structure, reveals the connection with the perovskite structure. Four Sr^{II} cations as in the perovskite structure occupy the A-sites with coordination number 12, another two Sr^{II} and two Nb^V cations alternatingly occupy the B-sites with coordination number 6, which is reduced to 5 wherever an oxide ion is missing, since 1/12 of the oxygen sites are unoccupied. Given a solid solution of this compound in the perovskite lattice of PZT, the result is a furthering of grain growth and contraction in the sintering process.

It has been found that $\text{Sr}_6\text{Nb}_2\text{O}_{11}$ has a phase range extending at high temperature far in the direction of a higher content of Nb_2O_5 and therefore it can be described by the general formula $\text{Sr}_{6-2x/3}\text{Nb}_{2+2x/3}\text{O}_{11+x}\text{V}_{1-x}$ or, adapting it to the cryolite structure, by $\text{Sr}_4(\text{Sr}_{2-2x/3}\text{Nb}_{2+2x/3})\text{O}_{11+x}\text{V}_{1-x}$ with $0 < x < 1$. Therefore, by using a content of Nb_2O_5 going beyond the composition of $\text{Sr}_6\text{Nb}_2\text{O}_{11}$, one can adjust the vacancy concentration and in this way produce a very advantageous material for piezoceramic applications, for example, in the system $[\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3]_{1-b-c}[\text{KNbO}_3]_b[\text{Sr}_4(\text{Sr}_{2-2x/3}\text{Nb}_{2+2x/3})\text{O}_{11+x}\text{V}_{1-x}]_c$ in the limits $0.5 < a < 0.6$; $0 < b < 0.5$; $0 < c < 0.05$; $0 < x < 1$, where V denotes a vacancy in the oxygen sublattice.

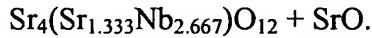
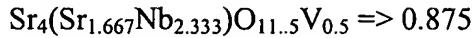
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The phase width of the cryolite component includes the possibility of a temperature-dependent variability for the oxygen vacancy concentration, for example, starting with the composition $\text{Sr}_4(\text{Sr}_{1.667}\text{Nb}_{2.333})\text{O}_{11..5}\text{V}_{0.5}$ with $x = 0.05$, at sinter temperature of 950 to 1200° C the solid solution of $\text{Sr}_4(\text{Sr}_2\text{Nb}_2)\text{O}_{11}\text{V}_1$ becomes effective with increased oxygen vacancy concentration according to the equation



and the liberated Nb_2O_5 is bound by the PbO content used as a sintering adjuvant as PbNb_2O_6 and incorporated into the PZT perovskite lattice with additional formation of vacancies at the A-sites. Due to the formation of oxygen vacancies, therefore, the system contains a mechanism which promotes sinter compaction under uniform grain growth.

Upon cooldown and tempering, on the other hand, the reverse process is to be taken into account by



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This leads to a reduction or elimination of the oxygen vacancy concentration, which is advantageous to the long-term stability of the voltage-loaded piezoceramic component, while the segregated SrO, being a stronger base, supplants PbO from the $\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3$ (PZT), i.e., some PbO is liberated and at the same time some $\text{Sr}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3$ (SZT) is formed, and this in turn enters into a solid solution with the PZT host lattice.

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Accordingly, $\text{Sr}_4(\text{Sr}_2\text{Nb}_2)\text{O}_{11}\text{V}_1$ can also be incorporated into the PZT host lattice as 0.75 $\text{Sr}_4(\text{Sr}_{1.333}\text{Nb}_{2.667})\text{O}_{12}$ without formation of oxygen vacancies or in all intermediate stages, in which case $\leq 2 \text{ Sr}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3$ (SZT) is formed and dissolved in the host lattice.

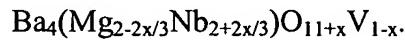
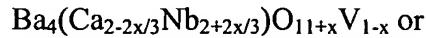
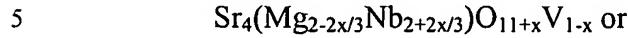
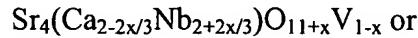
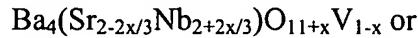
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Likewise, $\text{Sr}_4(\text{Sr}_{1.333}\text{Nb}_{2.667})\text{O}_{12}$ itself can act as a source of oxygen vacancies, by incorporating 0.889 $\text{Sr}_4(\text{Sr}_2\text{Nb}_2)\text{O}_{11}\text{V}_1$ or in one of the intermediate stages, and forming ≤ 0.444 of PbNb_2O_6 , whose solid solution in the PZT perovskite lattice involves the formation of vacancies at A-sites.

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Instead of $\text{Sr}_4(\text{Sr}_{2-2x/3}\text{Nb}_{2+2x/3})\text{O}_{11+x}\text{V}_{1-x}$, one can also use components with a cryolite structure, which contain Ba^{II} ions instead of Sr^{II} cations at the A-sites, and Ca^{II}

ions or Mg^{II} ions instead of Sr^{II} cations at the B-sites. This results in the following formulations for added components:



In this way, the range of variation of possible modifications of PZT ceramics is yet
10 again substantially broadened.

A further diversity is produced in that, besides these modifications by compounds with a cryolite structure, one should consider not only $KNbO_3$ as a further added components, but also only can use one of the already mentioned perovskite components
15 $Pb(M^{II}_{1/3}M^V_{2/3})O_3$ (M^{II} : Mg, Zn, Co, Ni, Mn, Cu and M^V : Nb, Ta, Sb) or $Pb(M^{II}_{1/2}M^{VI}_{1/2})O_3$ (M^{II} : Mg, Zn, Co, Ni, Mn, Cu and M^{VI} : W) or $Pb(M^{III}_{1/2}M^V_{1/2})O_3$ (M^{III} : Fe, Mn, Cr, Ga and M^V : Nb, Ta, Sb) or $Pb(M^{III}_{2/3}M^{VI}_{1/3})O_3$ (M^{III} : Fe, Mn, Cr, Ga and M^{VI} : W) and possibly also $Pb(M^I_{1/4}M^V_{3/4})O_3$ (M^I : Li, with M^V : Nb, Ta, Sb) and their mixtures.

20 This can be realized as additives with solid solution in the PZT perovskite lattice. Since it is always a question of these additives, compatible with the perovskite structure,

being taken up by the perovskite host lattice, mixtures of the five mentioned versions should likewise be taken into account.

The large range of variation of the solutions described thus far is rounded out by
5 formulas without valency compensation for mixed B-site occupancy, corresponding to a doping by so-called "soft" additives with partial compensation by mixing in some "hard" components, from which vacancies result in the perovskite lattice, having an especially advantageous impact on the grain formation in the sintering process, as well as the piezoelectrical and piezomechanical functional properties.

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The variability described here for the properties of a PZT ceramic, such as is brought about by the incorporation of a cryolite phase with phase width, is distinguished in that the advantageous combination of so-called soft with hard components can be influenced and thereby specifically adjusted through the ratio of niobium to strontium or
15 to one of the other alkaline earth elements and also by the temperature management.

The invention shall be explained more closely by the following sample embodiments and the accompanying figure.

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The figure shows a piezo-actuator in a schematic lengthwise cross section.

The figure shows a segment of a piezo-actuator 1, which is fabricated making use of the ceramic material described herein. One notices a stack of superimposed piezoelectrical ceramic layers 2, with electrode layers 3 lying in between. The piezo-actuator 1, moreover, has outer electrodes 4 on the ceramic body at the side. The making 5 of the piezo-actuator 1 shown in the figure occurs by forming ceramic green films, which are made from one of the ceramic materials described herein. A plurality of these green films, for example, 10 or even 100 of them, are stacked one on top of another. Between the ceramic green films are arranged electrode layers 3. The electrode layers 3 can consist of silver and palladium, for example. But the electrode layers 3 can just as well consist of copper. The electrode layers 3 can be placed on the individual ceramic green films, for example, by a silk screen process. The stacked ceramic green films are pressed together and then mutually debonded and sintered.

10 The result is a monolithic ceramic body with a stack of superimposed piezoelectric ceramic layers 2. The inner electrode layers 3 have structures meshing together as a comb, and every other electrode layer 3 makes contact with the very same outer electrode 4.

15 The electrical voltage needed for the electrical characterization of the piezo-actuator 1 is applied between the outer electrodes 4.

20 In order to make a ceramic material as described herein, one mixes a raw material mixture consisting of Pb_3O_4 or $PbCO_3$, TiO_2 , ZrO_2 , or a precursor $(Zr, Ti)O_2$ prepared by

mixture precipitation, as well as SrCO_3 and Nb_2O_5 and possibly other additives, such as KNbO_3 or $\text{Pb}(\text{Fe}_{0.5}\text{Nb}_{0.5})\text{O}_3$ corresponding to one of the sample compositions indicated in tables 1 to 16, in molar percent, or one can also use a mixture with the respective proportion of previously prepared cryolite phase.

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Tables 1 to 6: Batches of a PZT ceramic $[\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3]_{1-b-c}[\text{KNbO}_3]_b[\text{Sr}_4(\text{Sr}_{2-2x/3}\text{Nb}_{2+2x/3})\text{O}_{11+x}\text{V}_{1-x}]_c + 0.01 \text{ PbO}$

Table 1

$a = 0.53$	$b = 0$	$c = 0.0049$	$x = 0.5$
$a = 0.53$	$b = 0$	$c = 0.0082$	$x = 0.5$
$a = 0.535$	$b = 0$	$c = 0.0044$	$x = 1.0$
$a = 0.535$	$b = 0$	$c = 0.0076$	$x = 1.0$
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

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TRANSLATION

14219-119US1/P2004,0032USN
PCT/DE2005/000045

Table 2

$[Pb(Zr_aTi_{1-a})O_3]_{1-b-c}[KNbO_3]_b[Sr_4(Ca_{2-2x/3}Nb_{2+2x/3})O_{11+x}V_{1-x}]_c \cdot 0.01 PbO$			
$a = 0.53$	$b = 0$	$c = 0.0049$	$x = 0.5$
$a = 0.53$	$b = 0$	$c = 0.0082$	$x = 0.5$
$a = 0.535$	$b = 0$	$c = 0.0044$	$x = 1.0$
$a = 0.535$	$b = 0$	$c = 0.0076$	$x = 1.0$
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

Table 3

$[Pb(Zr_aTi_{1-a})O_3]_{1-b-c}[KNbO_3]_b[Sr_4(Mg_{2-2x/3}Nb_{2+2x/3})O_{11+x}V_{1-x}]_c \cdot 0.01 PbO$			
$a = 0.53$	$b = 0$	$c = 0.0049$	$x = 0.5$
$a = 0.53$	$b = 0$	$c = 0.0082$	$x = 0.5$
$a = 0.535$	$b = 0$	$c = 0.0044$	$x = 1.0$
$a = 0.535$	$b = 0$	$c = 0.0076$	$x = 1.0$
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

TRANSLATION

14219-119US1/P2004,0032USN
PCT/DE2005/000045

Table 4

$[Pb(Zr_{a}Ti_{1-a})O_3]_{1-b-c}[KNbO_3]_b[Ba_4(Sr_{2-2x/3}Nb_{2+2x/3})O_{11+x}]_{1-x}$			
$c = 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0$	$c = 0.0049$	$x = 0.5$
$a = 0.53$	$b = 0$	$c = 0.0082$	$x = 0.5$
$a = 0.535$	$b = 0$	$c = 0.0044$	$x = 1.0$
$a = 0.535$	$b = 0$	$c = 0.0076$	$x = 1.0$
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

Table 5

$[Pb(Zr_{a}Ti_{1-a})O_3]_{1-b-c}[KNbO_3]_b[Ba_4(Ca_{2-2x/3}Nb_{2+2x/3})O_{11+x}]_{1-x}$			
$c = 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0$	$c = 0.0049$	$x = 0.5$
$a = 0.53$	$b = 0$	$c = 0.0082$	$x = 0.5$
$a = 0.535$	$b = 0$	$c = 0.0044$	$x = 1.0$
$a = 0.535$	$b = 0$	$c = 0.0076$	$x = 1.0$
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

Table 6

$[Pb(Zr_aTi_{1-a})O_3]_{1-b-c}[Nb_2O_3]_b[Ba_4(Mg_{2-2x/3}Nb_{2+2x/3})O_{11+x}]^{V_{1-x}}$ $x \cdot c = 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0$	$c = 0.0049$	$x = 0.5$
$a = 0.53$	$b = 0$	$c = 0.0082$	$x = 0.5$
$a = 0.535$	$b = 0$	$c = 0.0044$	$x = 1.0$
$a = 0.535$	$b = 0$	$c = 0.0076$	$x = 1.0$
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

Tables 7 to 12:

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Batches of a PZT ceramic $[Pb(Zr_aTi_{1-a})O_3]_{1-b-c}[Pb(Fe^{III}_{1/2}Nb^V_{1/2})O_3]_b$, modified by additions of compounds with cryolite structure.

TRANSLATION

14219-119US1/P2004,0032USN
PCT/DE2005/000045

Table 7

$[\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3]_{1-b-c}[\text{Pb}(\text{Fe}^{\text{III}}_{1/2}\text{Nb}^{\text{V}}_{1/2})\text{O}_3]_b[\text{Sr}_4(\text{Sr}_{2-x}2x/3\text{Nb}_2+2x/3)\text{O}_{11+x}\text{V}_{1-x}]_c + 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0.003$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.008$	$c = 0.0035$	$x = 0.5$

Table 8

$[\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3]_{1-b-c}[\text{Pb}(\text{Fe}^{\text{III}}_{1/2}\text{Nb}^{\text{V}}_{1/2})\text{O}_3]_b[\text{Sr}_4(\text{Ca}_{2-x}2x/3\text{Nb}_2+2x/3)\text{O}_{11+x}\text{V}_{1-x}]_c + 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

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Table 9

$[\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3]_{1-b-c}[\text{Pb}(\text{Fe}^{\text{III}}_{1/2}\text{Nb}^{\text{V}}_{1/2})\text{O}_3]_b[\text{Sr}_4(\text{Mg}_{2-x}2x/3\text{Nb}_2+2x/3)\text{O}_{11+x}\text{V}_{1-x}]_c + 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

TRANSLATION

14219-119US1/ P2004,0032USN
PCT/DE2005/000045

Table 10

$(\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3)_{1-b-c}[\text{Pb}(\text{Fe}^{\text{III}}_{1/2}\text{Nb}^{\text{V}}_{1/2})\text{O}_3]_b[\text{Ba}_4(\text{Sr}_{2-2x/3}\text{Nb}_{2+2x/3})\text{O}_{11+x}\text{V}_{1-x}]_c + 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

Table 11

$(\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3)_{1-b-c}[\text{Pb}(\text{Fe}^{\text{III}}_{1/2}\text{Nb}^{\text{V}}_{1/2})\text{O}_3]_b[\text{Ba}_4(\text{Ca}_{2-2x/3}\text{Nb}_{2+2x/3})\text{O}_{11+x}\text{V}_{1-x}]_c + 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

5

Table 12

$(\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3)_{1-b-c}[\text{Pb}(\text{Fe}^{\text{III}}_{1/2}\text{Nb}^{\text{V}}_{1/2})\text{O}_3]_b[\text{Ba}_4(\text{Mg}_{2-2x/3}\text{Nb}_{2+2x/3})\text{O}_{11+x}\text{V}_{1-x}]_c + 0.01 \text{ PbO}$			
$a = 0.53$	$b = 0.002$	$c = 0.0047$	$x = 1.0$
$a = 0.53$	$b = 0.007$	$c = 0.0035$	$x = 0.5$

Said raw material mixtures are adjusted to the MPB in terms of the ratio of Zr to Ti and provided with a slight excess of PbO (around 2%) as sintering adjuvant, as appropriate, subjected to a grinding stage in aqueous suspension for an equal distribution of the components, and calcined at 900 to 950° C after being filtered and dried. With this,
5 the piezoceramic perovskite mixed crystal phase is already essentially formed.

By means of a subsequent fine grinding, one can adapt the sinter activity to the sinter temperature of around 1120° C for Ag/Pd inner electrodes (75/25) or 1000° C for Cu inner electrodes. In order to accomplish a sinter compaction already at 1000° C below
10 the melting temperature of copper, a fine grinding down to an average grain size of < 0.4 µm is required. The sinter activity of the powder will then be sufficient to ensure a compaction of >96% of the theoretical density, while at the same time having adequate grain growth and sufficient mechanical strength in the ceramic grain structure.

15 The finely ground powder is suspended by means of a dispersing agent into a watery slip with around 70 mass % solids content, corresponding to around 24 vol. %, and either converted into a pressable granulate by spraying or processed into ceramic green films. The proportion of dispersing agent needed for an optimal dispersion is ascertained separately in a series of experiments, and can be identified by achieving a minimum
20 viscosity. To the dispersed suspensions of solid powders one adds 6-8 mass % of a bonding agent to achieve the processing properties needed for the film drawing process:

binding agent on polyacrylate base or PVA base, e.g., polyvinylbutyral PVB, for multilayer piezo-components, e.g., actuators, with Ag/Pd inner electrodes; or one can use the thermohydrolytically more easily decomposed polyurethane in the case of a construction with Cu inner electrodes. After homogenization of the suspension, adjusted 5 in this way to an optimal viscosity and surface tension, in a Dispermat mill, one obtains a slip suitable for the film drawing process.

Disk-shaped moldings, prepared from the granulate, or square multilayer plates (MLP), obtained by stacking and laminating the green films 40 to 50 µm thick, can be 10 debonded in standard fashion, as can multilayer piezo-components, such as piezo-actuators, with up to 360 Ag/Pd inner electrodes. In the case of Cu inner electrodes, one must maintain an oxygen partial pressure below the oxidation of copper during both the debonding and the sintering, which is achieved by having a controlled H₂O/H₂ atmosphere, whose composition conforms to the kiln curve in the two thermal processes.

15

PZT ceramic samples debonded in this way enable a sinter compaction to yield a ceramic with advantageous grain structure for the piezoelectrical and piezomechanical properties. After producing contacts by sputtering of Au electrodes, one measures the dielectrical and especially the piezoelectrical properties of the resulting disk-shaped 20 samples with dimensions of around 10 x 10 mm² and thickness of 0.7 or 2 mm. In the case of multilayer components, such as actuator specimens, one produces contacts by depositing and baking a bondable Ag or Cu termination.

The polar condition of the ferroelectric ceramic with a Curie temperature of 250 to 380° C, depending on composition, is adjusted by poling with around 2 kV/mm. Several of the piezoelectrical properties obtained on such specimens are presented in Table 9 for 5 the piezoceramics modified with cryolite, as an example. For comparison, values for a soft ceramic doped with Nd are also given in Table 10. Besides the dielectric constant ϵ , the strain S under the action of the electrical field strength E was also measured according to the relation for the piezoelectric effect $S_3 = d_{33} \times E_3$ to determine the charge constant d (the index 3 denotes the direction of the polar axis, adjusted by poling, and the applied 10 field strength). Furthermore, the specific energy and the loss factor are indicated.

Table 13: Several properties determined in the small-signal and large-signal measurement mode for disk-shaped specimens of MLP (11 x 11 mm²) and actuators with Ag/Pd inner electrodes ($n = 350$, dielectric thickness $d = 80 \mu\text{m}$, 6.8 x 6.8 mm²) based on 15 the ceramic $[\text{Pb}(\text{Zr}_a\text{Ti}_{1-a})\text{O}_3]_{1-b-c}[\text{KNbO}_3]_b[\text{Sr}_4(\text{Sr}_{2-2x/3}\text{Nb}_{2+2x/3})\text{O}_{11+x}\text{V}_{0;1-x}]_c \cdot 0.01 \text{ PbO}$

TRANSLATION

14219-119US1/P2004,0032USN
PCT/DE2005/000045

	dielectric ϵ constant	d_{33} m/V	$\frac{\epsilon \cdot \epsilon_0}{d^2}$	J/m^3 loss factor or loss %
$[\text{Pb}(\text{Zr}_{0.53}\text{Ti}_{0.47})\text{O}_3] \cdot [\text{Sr}_{5.667}\text{Nb}_{2.333}\text{O}_{11.5}\text{V}_{0.5}]_{0.0049} + 0.01 \text{ PbO}$				
2 V/mm	1662	---	---	0.0177
2 kV/mm	2708	$731 \cdot 10^{-12}$	$4.49 \cdot 10^{-10}$	44.1 %
$[\text{Pb}(\text{Zr}_{0.535}\text{Ti}_{0.465})\text{O}_3] \cdot [\text{Sr}_{5.333}\text{Nb}_{2.667}\text{O}_{12}]_{0.0044} + 0.01 \text{ PbO}$				
2 V/mm	1742	---	---	---
2 kV/mm	2881	$722 \cdot 10^{-12}$	$4.89 \cdot 10^{-10}$	46.9 %
$[\text{Pb}(\text{Zr}_{0.53}\text{Ti}_{0.47})\text{O}_3] \cdot [\text{KNbO}_3]_{0.002} [\text{Sr}_{5.333}\text{Nb}_{2.667}\text{O}_{12}]_{0.0047} + 0.01 \text{ PbO}$				
2 V/mm	1716	--	--	0.0178
2 kV/mm	2837	$746 \cdot 10^{-12}$	$4.51 \cdot 10^{-10}$	45.8 %
$[\text{Pb}(\text{Zr}_{0.53}\text{Ti}_{0.47})\text{O}_3] \cdot [\text{KNbO}_3]_{0.007}$ $[\text{Sr}_{5.667}\text{Nb}_{2.333}\text{O}_{11.5}\text{V}_{0.5}]_{0.0035} + 0.01 \text{ PbO}$				
2 V/mm	1675	---	---	0.0162
2 kV/mm	2827	$688 \cdot 10^{-12}$	$5.29 \cdot 10^{-10}$	47.0 %

Table 14: Several properties determined in the small-signal and large-signal measurement mode for disk-shaped specimens of MLP (11 x 11 x 0.7 mm³) and actuators

TRANSLATION

14219-119US1/ P2004,0032USN
PCT/DE2005/000045

with Ag/Pd inner electrodes ($n = 350$, dielectric thickness $d = 80 \mu\text{m}$, $6.8 \times 6.8 \text{ mm}^2$)

based on the ceramic $\text{Pb}_{0.97}\text{Nd}_{0.02}\text{V}_{0.01}(\text{Zr}_{0.54}\text{Ti}_{0.46})\text{O}_3$ for MLP specimens and based on

$\text{Pb}_{0.96}\text{Nd}_{0.02}\text{Ag}_{0.02}(\text{Zr}_{0.54}\text{Ti}_{0.46})\text{O}_3$ for actuators with Ag/Pd inner electrodes

		dielectric constant ϵ	d_{33} in m/V	$(\epsilon \epsilon_0 / d_{33}^2)$ in J/m^3	loss factor or loss %
MLP	$E = 2 \text{ V/mm}$				
	$E=2 \text{ kV/mm}$	2420	$661 \cdot 10^{-12}$	$4.92 \cdot 10^{10}$	$\eta = 45 \%$
Ak-	$B = 2 \text{ V/mm}$	2708			$\tan \delta = 0.016$
toz	$P = 2 \text{ kV/mm}$	3534	$780 \cdot 10^{-12}$	$5.14 \cdot 10^{10}$	$\eta = 45 \%$

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14219-119US1/ P2004,0032USN
PCT/DE2005/000045

List of reference numbers

- 1 piezo-actuator
2 ceramic layers
5 3 electrode layers
4 outer electrodes